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# Simplified green-emitting single-layer phosphorescent organic light-emitting diodes with an external quantum efficiency > 22 %

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## Abstract

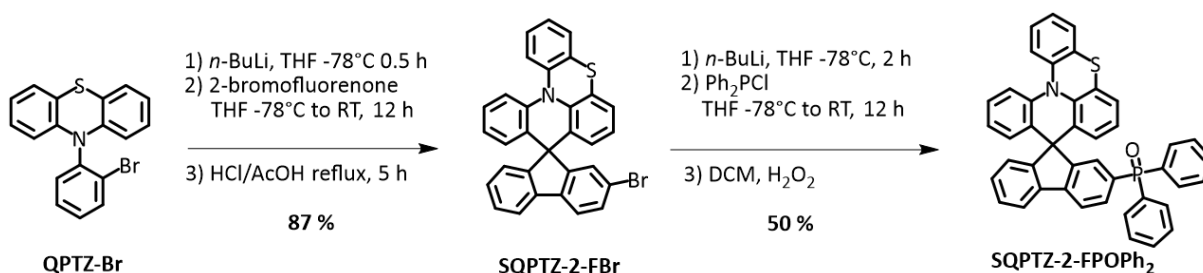
Nowadays, Phosphorescent Organic Light-Emitting Diodes (PhOLEDs) is a widespread technology, in which all the high-performance devices are constructed on a stack of different organic layers called multi-layer devices (ML-PhOLEDs). Thanks to these functional layers, the injection, the transport and the recombination of holes and electrons in the Emissive Layer (EML) are significantly improved allowing to reach high performances. In this technology, the ideal devices are the Single-Layer PhOLEDs (SL-PhOLEDs), with a very simple stack only constituted of the electrodes and the EML. These devices are simple, very easy to fabricate and can hence significantly decrease their costs. Nevertheless, removing the functional layers of an OLED drastically decreases the performances and there is, so far, only a few examples of high performances SL-PhOLEDs. Thus, in SL-PhOLEDs, the role of the functional layer should be done by the EML, which should allow an excellent injection, transport and recombination of holes and electrons. In this work, thanks to a rational molecular design of the EML, we report a green emitting SL-PhOLED displaying a very high external quantum efficiency of 22.7 %. The EML of this device is constructed on the barely studied Ir(ppy)<sub>2</sub>acac phosphor and a high efficiency host material possessing a Donor-*spiro*-Acceptor design. This performance is, to the best of our knowledge, the highest reported for SL-PhOLEDs (all colours considered). Through a structure/properties/device performance relationship study combining morphological (AFM), photophysical (time-resolved spectroscopy) and charge transport (SCLC) studies, we show that the EML presents all the required characteristics such as smooth surface, quick radiative deactivation and ambipolarity. In addition, the comparison with Ir(ppy)<sub>3</sub>, the most famous green emitter used in PhOLEDs highlights the high potential of Ir(ppy)<sub>2</sub>acac. The impact of the phosphorescent emitter on the ambipolarity of the charge transport is particularly evidenced.

## Introduction:

Phosphorescent Organic Light Emitting Diodes (PhOLEDs) are the 2<sup>nd</sup> generation of OLEDs<sup>1-5</sup> (1<sup>st</sup> generation: fluorescent OLEDs<sup>6-8</sup> / 3<sup>rd</sup> generation: thermally activated delayed fluorescence (TADF) OLEDs.<sup>9-12</sup>) PhOLEDs use a host-guest emissive layer (EML) in which the guest is an organometallic phosphorescent complex dispersed into an organic semiconductor (OSC), called host material. In a PhOLED, the maximal internal quantum efficiency (IQE<sub>max</sub>) is of 100 % as both triplet (75 %) and singlet (25 %) excitons can be recovered on the contrary to fluorescent OLEDs (IQE<sub>max</sub> of 25 %). Among the three generations of OLEDs, the PhOLED is the most mature device. The external quantum efficiencies (EQEs) of the most efficient PhOLEDs reported nowadays are very high, above 30 %.<sup>13, 14</sup> Green- and red-emitting devices are already part of lighting displays available on the market.<sup>2</sup> This achievement has been possible thanks to the development of hundreds of host materials for the last 20 years.<sup>15-20</sup> Beside molecular engineering, the architecture of the device itself is of great importance to maximize the conversion of electric energy into luminous energy.<sup>21-23</sup> In this context, the most performant PhOLEDs to date are constructed on a multi-layer (ML) stack, which insures a good injection, transport and recombination of holes and electrons in the EML.<sup>13, 14, 23-26</sup> Nevertheless, these devices remain complicated and simplifying the OLED technology is an important goal to decrease the production cost and the environmental footprint. One way to reduce these two main drawbacks is to use single-layer PhOLEDs (SL-PhOLEDs), which are the simplest possible OLED.<sup>15</sup> In this kind of simplified architecture, the intermediate functional layers are removed and only the EML remains. Thus, in SL-PhOLEDs, the host material is more than ever the cornerstone of this simplified technology, as it should play the role of all the functional layers of ML-PhOLEDs. In such a material, several properties must be gathered: (i) a triplet state energy (E<sub>T</sub>) higher than that of the phosphorescent emitter to confine the triplet excitons within the latter and allowing its single emission, (ii) high and equilibrated mobilities of electrons and holes (ambipolar character) to maximise excitons recombination within the centre of the EML and avoid leaks through the electrodes, (iii) HOMO and LUMO levels aligned with the Fermi level of the anode and the cathode to maximise holes and electrons injection respectively and (iv) good thermal and morphological stabilities to extend the OLED lifetimes.

Based on a *D-spiro-A* molecular design,<sup>27-37</sup> we developed, in this work, a very high-efficiency bipolar host for green SL-PhOLEDs namely spiroquinolinophenothiazine-2-diphenylphosphine oxide-fluorene (**SQPTZ-2-FPOPh<sub>2</sub>**) built on the combination of an electron-rich quinolinophenothiazine (QPTZ) fragment and an electron-deficient diphenylphosphine oxide-fluorene fragment (FPOPh<sub>2</sub>). The QPTZ fragment is a building unit, which has shown, in recent years, promising features for electronic applications<sup>37, 38</sup> and phosphine oxide is known to be a high efficiency electron-accepting unit.<sup>15, 39</sup> The present bipolar host possesses all the above-mentioned required properties apart from the ambipolar character. An important finding in this work is indeed connected to the fact that we notice that using this **SQPTZ-2-FPOPh<sub>2</sub>** host, ambipolarity can be achieved thanks to the

phosphorescent dopant. Thus, an EML composed of **SQPTZ-2-FPOP<sub>h2</sub>** as host and Ir(ppy)<sub>2</sub>acac as phosphorescent dopant achieves, in a SL-PhOLED, extremely high EQE and luminance of 22.7 % and 50920 cd.m<sup>-2</sup> respectively. To the best of our knowledge, these performances are the highest reported for SL-PhOLEDs (whatever the emitted colour) and shows that simplified SL-PhOLEDs can be almost as efficient as ML-PhOLEDs. We shed light on the key parameters involved in these high efficiencies, particularly the charge transport and the emission lifetime of the EML. The key role of the dopant in the charge transport and emission properties is particularly discussed. This type of simplified devices appears nowadays as a credible alternative to the well-known multi-layer technology for the future of OLEDs.



Scheme 1. Synthesis of **SQPTZ-2-FPOP<sub>h2</sub>**

In addition to the device simplification developed below, simplifying the synthetic approach is also a mandatory step to reduce both the environmental footprint and production cost. The approach developed herein is short, high yielding (44 % from QPTZ-Br) and low cost (approx. 0.5 € per gram for 2-bromofluorenone and less than 0.1 € per gram for phenothiazine) and has allowed to obtain **SQPTZ-2-FPOP<sub>h2</sub>** at the gram scale in a simple and efficient manner (Scheme 1). It should also be mentioned that this route does not use any Pd catalyst, a key point for real life application.

The electrochemical properties of **SQPTZ-2-FPOP<sub>h2</sub>** have been studied by cyclic voltammetry (CV) in CH<sub>2</sub>Cl<sub>2</sub> for oxidation (Figure 1, middle) and in DMF for reduction (Figure 1, left). The potentials discussed below are provided versus a saturated calomel electrode (SCE). In oxidation, the first wave is reversible with a maximum at 0.93 V. As the HOMO is centred on the QPTZ core (Figure 1, middle), the first electron transfer is assigned to the oxidation of this molecular fragment. This wave provides a high HOMO energy level of -5.20 eV, which translates the electron rich nature of the QPTZ fragment. This value is higher than those reported with the famous phenylacridine fragment, largely used in the design of OSCs (from - 5.33 to - 5.26 eV).<sup>28, 31, 40</sup>

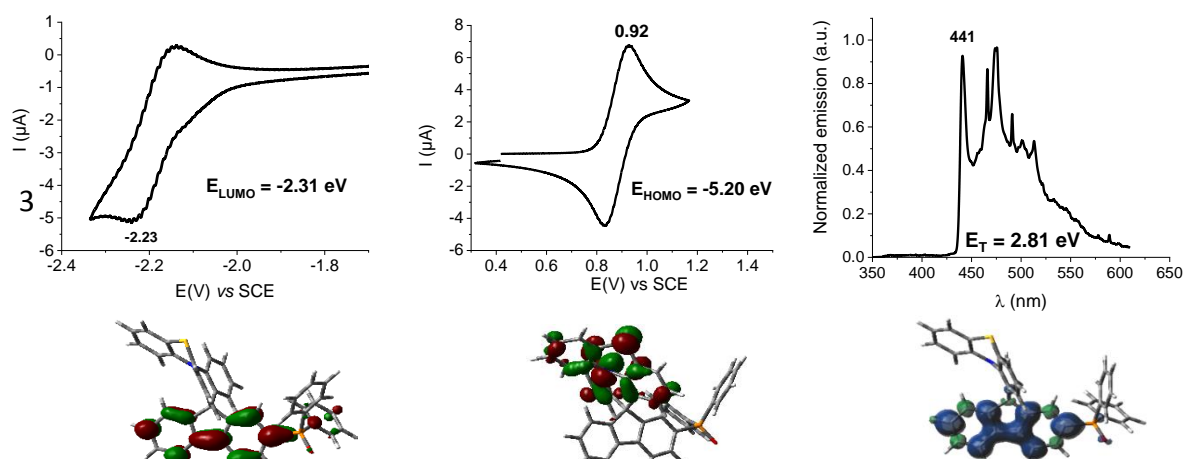


Figure 1. Cyclic voltammetry in reduction (left, DMF + Bu<sub>4</sub>NPF<sub>6</sub> 0.1 M, sweep-rate 100 mV.s<sup>-1</sup>) and in oxidation (middle, CH<sub>2</sub>Cl<sub>2</sub> + Bu<sub>4</sub>NPF<sub>6</sub> 0.2 M, sweep-rate 100 mV.s<sup>-1</sup>) and emission spectrum at 77 K (2-MeTHF) of **SQPTZ-2-FPOPh<sub>2</sub>**. From left to right inserted images are LUMO and HOMO electronic densities and spin density distribution of the first triplet state (TD-DFT B3LYP/6-311+G(d,p)).

In reduction, a reversible wave displaying a maximum at -2.23 V is detected. This wave is assigned to the reduction of the fluorene/phosphine oxide unit (Figure 1, left), giving a LUMO energy level of -2.31 eV. Thus, thanks to the *spiro* carbon, the electron-donating fragment and the electron-accepting fragment are spatially separated, which leads to a HOMO fully driven by the donor part and a LUMO fully driven by the acceptor part, according to TD-DFT calculations (see SI for details). In addition, electrochemical studies reveal that both first oxidation and reduction waves are reversible, showing the capability of **SQPTZ-2-FPOPh<sub>2</sub>** to transport both type of charges, which is a key feature in simplified PhOLEDs. Finally, the electrochemical gap ( $\Delta E_{\text{el}}$ ) is relatively small, measured at 2.89 eV, with HOMO/LUMO energy levels (-5.20/-2.31 eV), in accordance with those of Ir(ppy)<sub>2</sub>acac<sup>28</sup> (-5.06/-2.20 eV), see Figure 2. All these characteristics are of great interest for the SL device applications targeted herein particularly for the injection of charges.

The emission spectrum of **SQPTZ-2-FPOPh<sub>2</sub>**, measured at 77K, reveals a first phosphorescent band at 441 nm, translating a high first triplet state energy level E<sub>T</sub> of 2.81 eV (Figure 1, right) with a lifetime of 3.73 s (see Figure S9). The triplet spin density distribution (SDD) calculated by TD-DFT (B3LYP/6-311+G(d, p), Figure 1, right), displays that this first triplet state is centred on the fluorene backbone with no contribution of the QPTZ fragment and a very small one for the diphenylphosphine oxide fragment.

Finally, **SQPTZ-2-FPOPh<sub>2</sub>** displays a very high decomposition (T<sub>d</sub> =396°C) and glass transition (T<sub>g</sub>= 150°C) temperatures (Figures S1-2), which are key properties for stability. Thus, thanks to the rigid *spiro* carbon bridge and the bulky diphenylphosphine oxide unit, the physical properties of **SQPTZ-2-FPOPh<sub>2</sub>** appear to be excellent and in accordance with an optoelectronic application.

It is now interesting to compare the electronic and physical properties of **SQPTZ-2-FPOPh<sub>2</sub>** with that of its analogue possessing two phosphine oxides attached at C2 and C7 (named **SQPTZ-2,7-FPOPh<sub>2</sub>** see molecular structure in ref <sup>41</sup>). Thus, the removal of one phosphine oxide in **SQPTZ-2-FPOPh<sub>2</sub>** increases the electronic density on the fluorene,

increasing in turn the LUMO energy level (-2.60 vs -2.31 eV). This feature is directly linked to the electron withdrawing capability of the phosphine oxides. The HOMO energy level is also slightly increased in **SQPTZ-2-FPOPh<sub>2</sub>** (-5.25 vs -5.20 eV) translating the connection between the two spiro connected fragment. The E<sub>T</sub> is also significantly impacted by the removal of one phosphine oxide and increases from 2.76 eV in **SQPTZ-2,7-FPOPh<sub>2</sub>** to 2.81 eV in **SQPTZ-2-FPOPh<sub>2</sub>**. As the E<sub>T</sub> is fully driven by the fluorene unit (and as the phosphorus atom does not completely break the conjugation), the presence of only one phosphine oxide unit increases the E<sub>T</sub>. It should nevertheless be noted that the presence of the two phosphine oxides in **SQPTZ-2,7-FPOPh<sub>2</sub>** improves both the T<sub>g</sub> and the T<sub>d</sub> compare to **SQPTZ-2-FPOPh<sub>2</sub>**.

In the light of these promising properties, **SQPTZ-2-FPOPh<sub>2</sub>** has been incorporated as host in green SL-PhOLEDs. Two different green phosphorescent emitters have been used in this study: the flagship Ir(ppy)<sub>3</sub> and Ir(ppy)<sub>2</sub>acac. The former has been widely used in both ML- and SL-PhOLEDs with EQEs higher than 30 and 20 % respectively.<sup>13-15, 42</sup> The later has been rarely used in ML-PhOLEDs<sup>43</sup> and even less in SL-PhOLEDs.<sup>41</sup> Indeed, in SL-PhOLEDs, only three examples have been reported to date with Ir(ppy)<sub>2</sub>acac and these devices all display low EQEs below 12 %.<sup>41, 44, 45</sup> However, this phosphor displays interesting characteristics such as a narrower emission band than that of Ir(ppy)<sub>3</sub> with full width at half maxima (FWHM) of 64 nm against 68 nm, respectively. CIE coordinates (x;y) of Ir(ppy)<sub>2</sub>acac complex are (0.34;0.63) and that of Ir(ppy)<sub>3</sub> are (0.31;0.63) which makes the former a greener emitter. Thus, to improve the diversity of green emitting phosphors in PhOLEDs, investigating new iridium complexes is particularly important and even more when display applications are targeted considering that the colour rendering is an important feature.

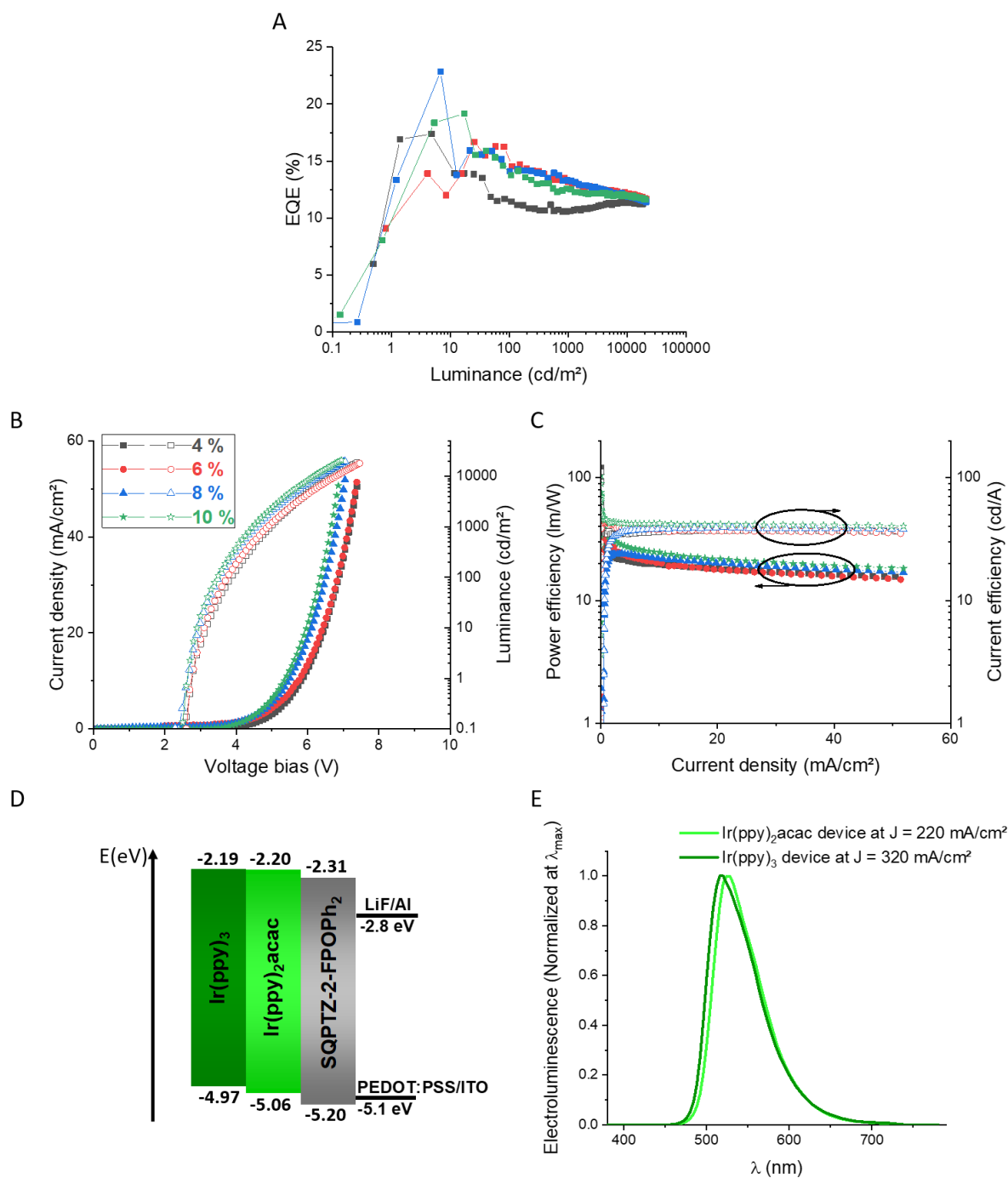


Figure 2. SL-PhOLEDs characteristics with **SQPTZ-2-FPOPh<sub>2</sub>**:Ir(ppy)<sub>2</sub>acac based EML at 4, 6, 8 and 10 % doping rate; (A) EQE (%) as a function of the luminance (cd/m<sup>2</sup>), (B) Current density (mA/cm<sup>2</sup>) and luminance (cd/m<sup>2</sup>) as a function of the bias voltage (V), (C) power efficiency (lm/W) and current efficiency (cd/A) as a function of the current density, (D) Simplified energetic diagram of the SL-PhOLEDs investigated and (E) electroluminescent spectra of SL-PhOLEDs incorporating **SQPTZ-2-FPOPh<sub>2</sub>** as host either doped with 8% of Ir(ppy)<sub>3</sub> (dark green) or with 8% of Ir(ppy)<sub>2</sub>acac (light green). The EML thickness of these devices is 100 nm.

The general SL-PhOLED structure used herein is : ITO/PEDOT:PSS (40 nm)/EML: **SQPTZ-2-FPOPh<sub>2</sub>** + p % Ir(ppy)<sub>2</sub>acac (100 nm)/LiF (1.2 nm)/Al (100 nm) with ITO/PEDOT:PSS as anode, LiF/Al as cathode and p is the doping rate. Before any device optimisation, classical conditions using found in SL-PhOLEDs have been first investigated, namely a doping rate (p) of 10 % and an EML thickness of 100 nm.<sup>28, 45-47</sup> In these conditions, **SQPTZ-2-FPOPh<sub>2</sub>** based SL-PhOLED exhibits a maximal external quantum efficiency (EQE<sub>max</sub>) of 19.3 % at 0.01 mA/cm<sup>2</sup>, a maximal luminance (L<sub>max</sub>) of 50330 cd/m<sup>2</sup> at 190 mA/cm<sup>2</sup> and a low threshold voltage (V<sub>on</sub>) of 2.7 V, Table 1. These performances are extremely high for simplified green SL-PhOLEDs and particularly for those incorporating Ir(ppy)<sub>2</sub>acac. Before this work, the highest EQE recorded with this dopant in a SL-PhOLED was significantly lower, measured at 11.3 %. It should be nevertheless noted that the potential of Ir(ppy)<sub>2</sub>acac (doped in CBP) has been previously highlighted in high efficiency ML PhOLEDs with EQE<sub>max</sub> 20.7%.<sup>43</sup> In addition, one can note that the low V<sub>on</sub> obtained at 0.1 cd/m<sup>2</sup> is slightly lower than the ΔE<sub>EI</sub> of **SQPTZ-2-FPOPh<sub>2</sub>** (see Figure 2), which indicates excellent charges injection in the host material. From a device engineering point of view, and particularly in a SL-PhOLED, the optimisation of the doping rate is important. However, when phosphorescent emitters are in play, quenching processes can happen such as triplet-triplet and triplet-polaron annihilations, which result in an important decrease of the performances, roll-off efficiency including, as the distance between guest molecules is decreasing.<sup>48</sup> So, an optimal doping rate must be found to prevent the quenching processes and maximise the transfers. Different doping rates p of 4, 6 and 8 % were then investigated. These devices yielded EQE<sub>max</sub> of 17.2, 17.8 and 22.7 % respectively, Table 1. All these performances are very high and all significantly higher than the state-of-the-art performances of Ir(ppy)<sub>2</sub>acac-based SL-PhOLEDs. This shows the high potential of **SQPTZ-2-FPOPh<sub>2</sub>** as host in simplified SL-PhOLEDs. In particular, the EQE<sub>max</sub> of 22.7 % obtained with a doping rate of 8 % is extremely high and, to the best of our knowledge, the highest reported in the literature for a simplified SL-PhOLED (whatever the emitter considered).<sup>42</sup> Finally, note that the doping rate is less marked at 10 mA/cm<sup>2</sup>, the EQEs are comprised between 11.3 and 11.9 %, see Table 1. This is an interesting finding as it indicates that even with a small amount of iridium complex very good performances can be obtained at high current density. From an industrialization point of view, this feature can result in lower production costs. The PhOLEDs performance at different luminance is found in Table 2. At 1000 cd.m<sup>-2</sup>, the performance of the most efficient OLED is 13.3% (corresponding CE of 47.3 cd/A and LE of 32.9 lm/W)

In PhOLED technology, the phosphorescent dopant is, obviously, of key importance not only in term of efficiency but also in term of stability and colour rendering. However, only a few are commonly used. To find out about the impact of the phosphor in SL-PhOLED, a series of devices with the **SQPTZ-2-FPOPh<sub>2</sub>** / Ir(ppy)<sub>3</sub> combination as EML have been fabricated, keeping the optimised doping rate of 8% and the same device architecture than that presented above. The corresponding SL-PhOLED yielded an EQE<sub>max</sub> of 17.9 % at 0.01 mA/cm<sup>2</sup>, a L<sub>max</sub> of 51020 cd/m<sup>2</sup> at 320 mA/cm<sup>2</sup> and a V<sub>on</sub> at 2.7 V (Table S5). There is hence a strong decrease of the EQE<sub>max</sub>, from 22.7 % with Ir(ppy)<sub>2</sub>acac to 17.9 % with Ir(ppy)<sub>3</sub>, which



can only be imputed to the emitter. At 10 mA/cm<sup>2</sup>, there is still a high difference of 3 % between the two phosphors (11.9 % for Ir(ppy)<sub>2</sub>acac device vs 8.7 % for Ir(ppy)<sub>3</sub> device). The luminance, measured at the same current density (220 mA/cm<sup>2</sup>), is also significantly higher for Ir(ppy)<sub>2</sub>acac than for Ir(ppy)<sub>3</sub>: 50920 cd/m<sup>2</sup> and 40850 cd/m<sup>2</sup> respectively. The origin of the difference between these two sets of devices and the very high performances obtained with the Ir(ppy)<sub>2</sub>acac based devices should then be unravelled.

Table 1 SL-PhOLED performances using **SQPTZ-2-FPOPh<sub>2</sub>** as host and Ir(ppy)<sub>2</sub>acac as phosphorescent dopant. Device architecture: ITO/PEDOT:PSS (40 nm)/host + p % dopant (100 nm)/LiF (1.2 nm)/Al (100 nm) where p is the doping rate.

p (%)	V <sub>on</sub> (V)	EQE (%)	CE (cd/A)	PE (lm/W)	L (cd/m <sup>2</sup> )	EQE (%)	CE (cd/A)	PE (lm/W)	L (cd/m <sup>2</sup> )	CIE coordinates (x ; y)
		At 10 mA/cm <sup>2</sup>				Max (at J (mA/cm <sup>2</sup> ))				At 10 mA/cm <sup>2</sup>
4	2.8	11.3	26.2	36.0	4093	17.2 (0.01)	56.0 (0.01)	56.1 (0.01)	47910 (170)	0.32 ; 0.64
6	2.8	12.2	24.7	42.9	4100	17.8 (0.02)	65.2 (0.02)	63.1 (0.02)	47700 (200)	0.32 ; 0.64
8	2.7	11.9	20.2	42.6	3923	22.7 (0.01)	87.8 (0.01)	81.0 (0.01)	50920 (220)	0.32 ; 0.64
10	2.7	12.5	25.4	43.4	4430	19.3 (0.01)	71.6 (0.01)	67.1 (0.01)	50330 (190)	0.34 ; 0.63

Table 2 SL-PhOLED performances at 1, 100 and 1000 cd/m<sup>2</sup> with **SQPTZ-2-FPOPh<sub>2</sub>**; Ir(ppy)<sub>2</sub>acac, at 4, 6, 8 or 10% doping ratio. Device structure: ITO/PEDOT:PSS (40 nm)/host + dopant (100 nm)/LiF (1.2 nm)/Al (100 nm).

p (%)	EQE (%)	CE (cd/A)	PE (lm/W)	EQE (%)	CE (cd/A)	PE (lm/W)	EQE (%)	CE (cd/A)	PE (lm/W)
	At 1 cd/m <sup>2</sup>			At 100 cd/m <sup>2</sup>			At 1000 cd/m <sup>2</sup>		
4	16.9	55.4	62.2	11.5	37.5	30.3	10.6	34.8	23.5
6	9.1	31.9	38.6	14.5	51.1	46.0	13.2	46.3	32.8
8	13.4	47.6	55.4	14.1	50.3	45.2	13.3	47.3	32.8
10	8.0	28.0	33.8	13.7	47.8	42.9	12.6	43.8	33.0

First, the morphology of the EML is known to have a great influence on the efficiency of an organic electronic device.<sup>49, 50</sup> Thus, we have investigated the roughness of both EMLs by performing AFM studies, Figure 3. Samples presenting the same architecture as the corresponding SL-PhOLEDs, *i.e.* ITO/PEDOT:PSS (40nm)/EML (100nm) were prepared.

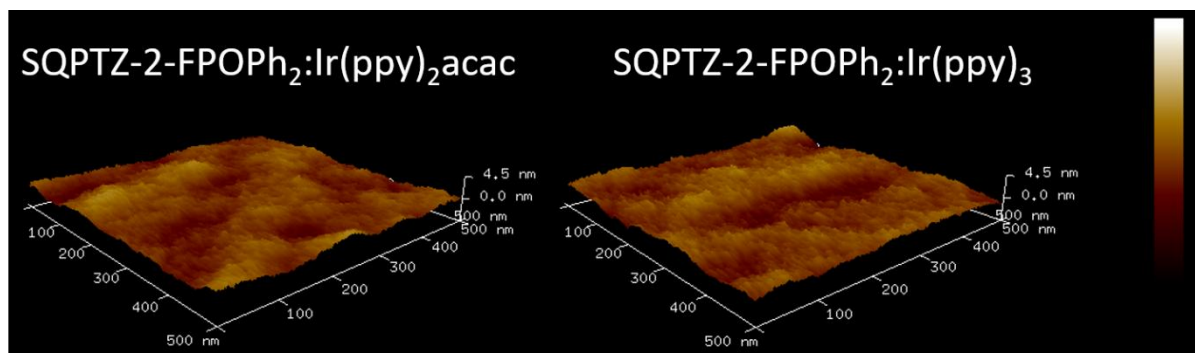


Figure 3 2D ( $500 \times 500 \text{ nm}^2$ ) AFM images of (left) **SQPTZ-2-FPOPh<sub>2</sub> + 8 % Ir(ppy)<sub>2</sub>acac** (100 nm) and (right) **SQPTZ-2-FPOPh<sub>2</sub> + 8 % Ir(ppy)<sub>3</sub>** (100 nm) EMLs.

The film surface of the Ir(ppy)<sub>2</sub>acac based EML presents a root mean surface roughness ( $R_q$ ) of 0.549 nm while the one of Ir(ppy)<sub>3</sub> based EML is 0.557 nm. These two  $R_q$  are really close and show that the morphology of the EMLs are not impacted by the nature of the dopant. From this point of view, the extraction of light might follow the same path for both. These values also show that the quality of the interfaces with PEDOT:PSS is identical, which is in accordance with the  $V_{ON}$ , 2.7 V for both sets of devices. This is a very interesting feature as it shows that the good performances obtained with both dopants are undoubtedly linked to this macroscopic characteristic. Nevertheless, to unravel the origin of the different performances between the two emitters, molecular interactions between the host and the two dopants should be considered. Kim and co-workers have shown that the orientation of the emitting dipoles is crucial to maximise the extraction of light, resulting in an increase of the  $EQE_{max}$ .<sup>51</sup> They have shown that the phosphorescent emitter Ir(ppy)<sub>2</sub>acac has preferential horizontal-directed emitting dipoles when it is 8 % doped in the exciplex forming co-host TCTA:B3PYMPM (1:1). This orientation allows to enhance the light extraction. Similarly, Wu and co-workers have compared the performances of ML-PhOLEDs using either Ir(ppy)<sub>3</sub> or Ir(ppy)<sub>2</sub>acac 8 % doped in CBP.<sup>52</sup> They have shown that, while Ir(ppy)<sub>3</sub> has randomly oriented emitting dipoles in the EML, the preferentially horizontal-directed emitting dipoles of Ir(ppy)<sub>2</sub>acac in the EML allow to increase the EQE of 2 to 3 %. In our study, we have observed the same improvement in term of EQE at  $10 \text{ mA.cm}^{-2}$ , going from 8.7 % for Ir(ppy)<sub>3</sub> device to 11.9 % for Ir(ppy)<sub>2</sub>acac device. Thus, the very high efficiency obtained with Ir(ppy)<sub>2</sub>acac-based EML can be due, at least partially, to a similar behaviour as that shown by Wu and co-workers, showing the potential of this phosphor in PhOLEDs.

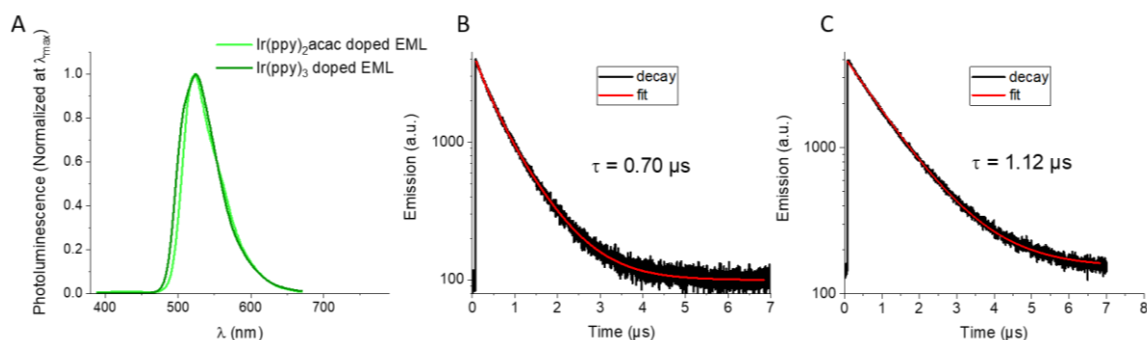


Figure 4 (A) Steady state photoluminescence spectra of the EML 8 % doped Ir(ppy)<sub>2</sub>acac ( $\lambda_{exc} = 366$  nm) or Ir(ppy)<sub>3</sub> ( $\lambda_{exc} = 340$  nm) into **SQPTZ-2-FPOPh<sub>2</sub>** and time resolved photoluminescence (B) of the EML 8 % doped with Ir(ppy)<sub>2</sub>acac ( $\lambda_{exc} = 310$  nm,  $\lambda_{em} = 525$  nm) and (C) of the EML 8 % doped with Ir(ppy)<sub>3</sub> ( $\lambda_{exc} = 310$  nm,  $\lambda_{em} = 525$  nm). The thickness of the EMLs is 100 nm.

To get additional insights on excitons transfers and photophysical mechanisms, we have performed steady state and time resolved spectroscopy experiments of the EML 8 % doped either with Ir(ppy)<sub>3</sub> or Ir(ppy)<sub>2</sub>acac, Figure 4. First of all, both EML present photoluminescence spectra matching with their corresponding electroluminescence spectra (Figure 2E and Figure 4A). This shows that excitons transfers from the host to the emitter are highly efficient and do not depend on the dopant used, highlighting the efficiency of the *D-spiro-A* molecular design. The radiative deactivation of the EML is also a very important data to insure an efficient emission and should also be considered. The Ir(ppy)<sub>2</sub>acac-based EML exhibits a lifetime decay below 1 μs ( $\tau = 0.70$  μs at  $\lambda_{em} = 525$  nm) while the Ir(ppy)<sub>3</sub>-based EML shows a longer lifetime decay with  $\tau = 1.12$  μs at the same emission wavelength. Therefore, the lifetime of the Ir(ppy)<sub>2</sub>acac-based EML is significantly reduced compared to that of Ir(ppy)<sub>3</sub>. The quicker radiative deactivation of the triplet state of the Ir(ppy)<sub>2</sub>acac complex can be related to the high efficiency reached due to a decrease of triplet-triplet annihilation.<sup>53-58</sup> Note that the link between high PhOLED performance and short deactivation lifetime of the EML has been recently highlighted in high performance ML-PhOLEDs.<sup>53</sup>

The charge transport within the EML should also be considered as a key feature to explain the high performance of the SL-PhOLEDs. In the field of SL-PhOLEDs, the ability of the host to transport both electrons and holes efficiently and as balanced as possible is an important property to maximise the formation of excitons preferably in the centre of the EML.<sup>15</sup> So, **SQPTZ-2-FPOPh<sub>2</sub>** has been incorporated in hole-only and electron-only space charge limited current (SCLC) devices to extract charge carriers mobilities (see SI for device architectures, fabrication processes and electrical characteristics). The hole ( $\mu_h$ ) and electron ( $\mu_e$ ) mobilities have been estimated at  $5.1 \pm 2.1 \times 10^{-8}$  and  $1.1 \pm 1.6 \times 10^{-4}$  cm<sup>2</sup>.V<sup>-1</sup>.s<sup>-1</sup>, respectively. Thus, **SQPTZ-2-FPOPh<sub>2</sub>** has a hole mobility 2000 times lower than its corresponding electron mobility. For a *spiro* compound, displaying a 3D shape, the electron mobility appears to be particularly high but the transport is not properly balanced, which is not in accordance with a very high SL-PhOLED performance. However, the impact of the iridium complex, present in

the EML, is not reflected by these data. The charge transport of the EML, including 8 % of Ir(ppy)<sub>2</sub>acac, was thus precisely determined through characterization of SCLC devices and has provided hole and electron mobilities of  $7.2 \pm 3.0 \times 10^{-7}$  and  $7.6 \pm 2.3 \times 10^{-6} \text{ cm}^2 \cdot \text{V}^{-1} \cdot \text{s}^{-1}$ . This leads to a  $\mu_e/\mu_h$  ratio of 11, close to unity. Surprisingly, we observed that the hole mobility is increased while the electron mobility is decreased compared to the neat host helping to reach a more balanced hole and electron transport. This balance of hole and electron flow within the EML appears as a central notion to insure an efficient charge recombination in the centre of the EML. The same experiments were conducted for the couple **SQPTZ-2-FPOPh<sub>2</sub>**/Ir(ppy)<sub>3</sub> and provides values of  $7.1 \pm 1.5 \times 10^{-8}$  and  $1.1 \pm 2 \times 10^{-5} \text{ cm}^2 \cdot \text{V}^{-1} \cdot \text{s}^{-1}$ . In this latter case, the  $\mu_e/\mu_h$  ratio (>140) is larger and less balanced than the Ir(ppy)<sub>2</sub>acac based EML displays a more balance charge transport than Ir(ppy)<sub>3</sub> based EML. In the light of the importance of ambipolarity in SL-PhOLEDs, one can consider that the higher performances obtained for Ir(ppy)<sub>2</sub>acac arises from this feature.

Finally, to ascertain the efficiency of the *D-Spiro-A* molecular design in the SL-PhOLED performance, Ir(ppy)<sub>2</sub>acac-based SL-PhOLEDs using two commercially available host materials, 4,4'-bis(*N*-carbazolyl)-1,1'-biphenyl (CBP, HOMO/LUMO: -5.56/-2.09 eV,  $E_T = 2.69$  eV) and 1,3-bis(*N*-carbazolyl)benzene (mCP, HOMO/LUMO: -5.64 / -1.90 eV,  $E_T = 3.05$  eV), have been fabricated. These hosts are commonly found in literature in high performance devices.<sup>24, 59-62</sup> For the purpose of this work and to keep consistency HOMO, LUMO and  $E_T$  levels of CBP and mCP have been measured in identical conditions than that used for **SQPTZ-2-FPOPh<sub>2</sub>** (see SI Figures S14-15 and Table S5). The architecture of these benchmark devices is identical to those reported above and the different performance can then only be ascribed to the host. The performances recorded for both compounds appear to be very low with EQE<sub>max</sub> of 1.3 % (CBP) and 2.6 % (mCP) measured at 10 mA/cm<sup>2</sup>.  $V_{ON}$  are very high, 4.6 and 4.1 V, and  $L_{max}$  very low, 1487 cd/m<sup>2</sup> (at 70 mA/cm<sup>2</sup>) and 1213 cd/m<sup>2</sup> (at 50 mA/cm<sup>2</sup>) for CBP and mCP respectively (see Figures S14-15 and Table S5). We attribute the poor performances of these two matrices to a poor electron transport in the host material as both of these matrices are only made on electron-donating carbazole moieties. This confirms the importance of the ambipolarity of the charge transport to achieve high efficiency SL-PhOLEDs.

To conclude, we report a high efficiency EML for SL-PhOLED, namely Ir(ppy)<sub>2</sub>acac as emitter and **SQPTZ-2-FPOPh<sub>2</sub>** as host material. Constructed on a *D-spiro-A* design, **SQPTZ-2-FPOPh<sub>2</sub>** gathers all required photophysical, electronic, thermal and morphological properties for high performance simplified green-emitting SL-PhOLEDs. One of the peculiarities of this work lies in the use of the barely studied Ir(ppy)<sub>2</sub>acac emitter, which appears significantly, in combination with our host molecule, more efficient than the well-known Ir(ppy)<sub>3</sub> emitter. An extremely high EQE of 22.7 % (CE = 87.8 cd/A, PE = 81.0 lm/W,  $V_{on} = 2.7$  V and  $L_{max} = 50920$  cd/m<sup>2</sup>) was reached with CIE coordinates of 0.32;0.64 at 10 mA/cm<sup>2</sup>, which is, to the best of our knowledge, the highest reported for this technology of simplified OLEDs (for all colour). Beside the good alignment of LUMO levels of the host material and the dopant, the high

performance arises from the excellent balance of the charge carriers within the EML, rapid radiative deactivation processes and smooth roughness surface. These characteristics appear to be more efficient to reach high performance than those of Ir(ppy)<sub>3</sub>, the flagship green emitter in PhOLED technology. These performances are also significantly higher than those of well-known commercially available host matrices, CBP and mCP, demonstrating the efficiency of the molecular design strategy. This work shows that the performance of SL-PhOLEDs are closer and closer to those of ML-PhOLEDs and bridges the gap between these two technologies.

### **Conflicts of interest**

There are no conflicts to declare.

### **Acknowledgements**

The author highly thank the Agence Nationale de la Recherche (Project *Spiroquest* N°19-CE05-0024) for PhD and post-doctoral grants (CB and FL respectively). The ADEME (*Ecoelec* Project) is also warmly acknowledged for PhD grant (CB). We also thank the CRMPO (Rennes) for mass analyses and GENCI (Project N°AD0100805032R1) for computing time.

### **Supporting Information**

General experimental methods, synthetic procedures, compounds characterizations, copy of mass and NMR spectra and thermal, photophysical, electrochemical, computational and devices data are provided.

### **General experimental methods**<sup>41</sup>

#### Synthesis

All manipulations of oxygen and moisture-sensitive materials were conducted with a standard Schlenk technique. All glassware was kept in an oven at a temperature of 80°C. Argon atmosphere was generated by three repetitive cycles of vacuum/Argon using a schlenk ramp. Commercially available reagents and solvents were used without further purification other than those detailed below. THF was obtained through a PURE SOLV™ solvent purification system. Light petroleum refers to the fraction with bp 40-60°C. Analytical thin layer chromatography was carried out using aluminum backed plates coated with Merck Kieselgel 60 GF254 and visualized under UV light (at 254 and 360 nm). Flash chromatography was carried out using Teledyne Isco CombiFlash® Rf 400 (UV detection 200-360 nm), over standard silica cartridges (Redisep® Isco or Puriflash® columns Interchim). <sup>1</sup>H and <sup>13</sup>C NMR spectra were recorded using Bruker 300 MHz instruments (<sup>1</sup>H frequency, corresponding <sup>13</sup>C frequency: 75 MHz); chemical shifts were recorded in ppm and J values in Hz. The residual signals for the NMR solvents used are 5.32 ppm (proton) and 53.84 ppm (carbon) for CD<sub>2</sub>Cl<sub>2</sub>.<sup>63</sup> In the <sup>13</sup>C NMR spectra, signals corresponding to C, CH, CH<sub>2</sub> or CH<sub>3</sub> groups, assigned

from DEPT experiment, are noted. The following abbreviations have been used for the NMR assignment: s for singlet, d for doublet, t for triplet, q for quadruplet and m for multiplet. High resolution mass spectra were recorded at the Centre Régional de Mesures Physiques de l'Ouest (CRMPO-Rennes) on a Thermo Fisher Q-Exactive instrument or a Bruker MaXis 4G or a Bruker Ultraflex III.

### Spectroscopic studies

Cyclohexane (spectroscopic grade, Acros) and 2-MeTHF (Anhydrous, >99 %, Sigma Aldrich) were used without further purification.

UV-visible spectra were recorded using an UV-Visible spectrophotometer SHIMADZU UV-1605. Molar extinction coefficients ( $\epsilon$ ) were calculated from the gradients extracted from the plots of absorbance vs concentration with five solutions of different concentrations for each sample.

$$A = \epsilon \times l \times C$$

Steady state and time resolved emission spectra were recorded with a HORIBA Scientific Fluoromax-4 equipped with a Xenon lamp. Triplet energy levels were calculated from the maximum of the first phosphorescence emission peak at 77 K. Conversion in electron-volt was obtained with the following formula:  $E_T(eV) = \frac{hc}{\lambda}$  with  $h = 6.62607 \times 10^{-34}$  J.s,  $C = 2.99792 \times 10^{17}$  nm.s<sup>-1</sup> and  $1 \text{ eV} = 1.60218 \times 10^{-19}$  J. This equation can be simplified as:  $E_T(eV) = \frac{1239.84}{\lambda}$  with  $\lambda$  formulated in nm.

Low temperature (77 K) measurements were performed in 2-MeTHF which freezes as a transparent glassy matrix. Measurements were carried in a single block quartz tube containing the solution, which was placed in an oxford Optistat Cryostat cooled with liquid nitrogen.

Infrared spectra were recorded on a Bruker Vertex 70 using a diamond crystal MIRacle ATR (Pike).

### Electrochemical studies

Electrochemical experiments were performed under argon atmosphere using a Pt disk electrode (diameter 1 mm). The counter electrode was a vitreous carbon rod. The reference electrode was either a silver wire in a 0.1 M AgNO<sub>3</sub> solution in CH<sub>3</sub>CN for the studies in oxidation or a Silver wire coated by a thin film of AgI (silver(I)iodide) in a 0.1 M Bu<sub>4</sub>NI solution in DMF for the studies in reduction. Ferrocene was added to the electrolyte solution at the end of a series of experiments. The ferrocene/ferrocenium (Fc/Fc<sup>+</sup>) couple served as internal standard. The three electrodes cell was connected to a potentiostat/galvanostat (Autolab/PGSTAT101) monitored with the Nova 2.1 Software. Activated Al<sub>2</sub>O<sub>3</sub> was added in the electrolytic solution to remove excess moisture. For a further comparison of the electrochemical and optical properties, all potentials are referred to the SCE electrode that

was calibrated at  $-0.405$  V vs.  $\text{Fc}/\text{Fc}^+$  system. We estimated the electron affinity (EA) or lowest unoccupied molecular orbital (LUMO) and the ionization potential (IP) or highest occupied molecular orbital (HOMO) from the redox data. The LUMO level was calculated from the cyclic voltammetry in reduction as follow:  $\text{LUMO (eV)} = -[E_{\text{onset}} (\text{vs SCE}) + 4.4]$ . Similarly the HOMO level was calculated from the cyclic voltammetry in oxydation as follow:  $\text{HOMO (eV)} = -[E_{\text{onset}} (\text{vs SCE}) + 4.4]$  based on an SCE energy level of  $4.4$  eV relative to the vacuum. The electrochemical gap was calculated from:  $\Delta E^{\text{el}} = |\text{HOMO-LUMO}|$  (in eV).

## Molecular modelling

Full geometry optimization of the ground state ( $S_0$ ) and vibrational frequency calculation were performed with Density Functional Theory (DFT)<sup>64, 65</sup> using the hybrid Becke-3 parameter exchange functional<sup>66-68</sup> and the Lee-Yang-Parr non-local correlation functional<sup>69</sup> (B3LYP) implemented in the Gaussian 16 program suite,<sup>70</sup> using the 6-31G(d) basis set and the default convergence criterion implemented in the program. All stationary points were characterized as minima by analytical frequency calculations. Optical transition diagrams were obtained through TD-DFT calculations performed using the B3LYP functionals and the 6-311+G(d,p) basis set from the optimized geometry of  $S_0$ . Geometry optimization of the first excited triplet state (T1) was performed using Time-Dependent Density Functional Theory (TD-DFT) calculations using the B3LYP functional and the 6-311+G(d,p) basis set. Spin density (SD) representation was obtained through TD-DFT calculations performed using the B3LYP functional and the extended 6-311+G(d,p) basis set and a triplet spin on the previously optimized geometry of T1. T1 to  $S_0$  energy transition (ET) was calculated from the difference between the total energy of the molecule in its respective excited triplet state (found trough TD- DFT, B3LYP 6-311+G(d,p)) and its ground singlet state (found through DFT, B3LYP 6-311+G(d,p)) in their optimized geometries.

Calculations were carried out on the OCCIGEN calculator of the Centre Informatique National de l'Enseignement Supérieur (CINES (Montpellier) under project N° 2021-A0100805032).

## Thermal analysis

Thermal Gravimetric Analysis (TGA) was carried out by using a Mettler-Toledo TGA-DSC-1 apparatus. TGA curved were measured at  $10^\circ\text{C}/\text{min}$  from  $30^\circ\text{C}$  to  $1000^\circ\text{C}$  under a nitrogen flux. Differential Scanning Calorimetry (DSC) was carried out by using a NETZSCH DSC 200 F3 instrument equipped with an intracooler DSC traces were measured at  $10^\circ\text{C}/\text{min}$ , 2 heating/cooling cycles were successively carried out under a nitrogen flux.

## Devices fabrication and characterization

- Single layer phosphorescent organic light emitting diodes (SL-PhOLEDs)

The structure of the SL devices is the following: ITO/PEDOT:PSS (40 nm)/Emissive layer *host:guest p %* (100 nm)/LiF (1.2 nm)/Al (100 nm). In this devices, ITO/PEDOT:PSS (poly(3,4-ethylenedioxythiophene)-poly(styrenesulfonate)) is used as the anode and a thin film of lithium fluoride covered with aluminum is the cathode. The devices have been fabricated onto patterned ITO coated glass substrates from XinYan Tech (thickness: 100 nm and sheet resistance: less of 20 W/m). The organic materials are deposited onto the ITO anode by sublimation under high vacuum ( $< 10^{-6}$  Torr) at a rate of 0.2 – 0.3 nm/s. The entire device is fabricated in the same run without breaking the vacuum. In this study, the thicknesses of the different organic layers were kept constant for all the devices. The active area of the devices defined by the overlap of the ITO anode and the metallic cathode was 0.3 cm<sup>2</sup>. The current-voltage-luminance (I-V-L) characteristics of the devices were measured with a regulated power supply (Laboratory Power Supply EA-PS 3032-10B) combined with a multimeter and a 1 cm<sup>2</sup> area silicon calibrated photodiode (Hamamatsu). The spectral emission was recorded with a SpectraScan PR650 spectrophotometer. All the measurements were performed at room temperature and at ambient atmosphere with no further encapsulation of devices.

- Space-charged limited current (SCLC) devices

*Fabrication of hole-only space-charge limited current (SCLC) devices:* Indium-tin oxide (ITO) coated glass was used as a substrate. A sequential cleaning of the substrates in soap water, distilled water, acetone and isopropanol (15 min for each step) using ultrasonic bath was performed. A thin, highly conductive poly(ethylenedioxythiophene):polystyrene sulfonate (PEDOT:PSS) layer was spin-coated onto pre-cleaned ITO and used as a bottom electrode. Then samples were thermally annealed at 120°C for 15 min. The active layer was co-evaporated under high vacuum ( $< 10^{-6}$  Torr) at a rate of 0.2 – 0.3 nm/s SCLC devices were completed by sequential thermal evaporation of MoO<sub>3</sub> (7nm) and Ag (250 nm) layers.

*Fabrication of electron-only space-charge limited current (SCLC) devices:* Identical ITO substrates and cleaning conditions were applied as for hole-only samples (see above). A thin ZnO layer (20-25 nm) was spin-coated onto pre-cleaned ITO and thermally annealed at 110°C for 10 min and used as a bottom contact. The active layer was deposited as previously for hole-only SCLC devices, devices were completed by a sequential evaporation of Ca (20 nm) and Al (300 nm) as a top contact.

SCLC diode current-voltage characteristics were measured, inside the glove-box, using Keithley semiconductor characterization system 4200. The active-layer thicknesses were measured after SCLC characterization using a profilometer.

#### Atomic force microscopy measurement

AFM images were recorded on the Bruker Multimode 8 using PeakForce Tapping with a resolution of 512x512 pixels on a 500nmx500nm surface. Scan rate has been set at 1Hz. Each scan line in the image was scanned from left to right (trace) and from right to left (retrace). The observed topographic features were verified for their consistency between trace and retrace images. Amplitude setpoint was set to 2.81mV and the drive amplitude was set to

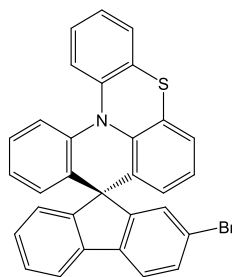


10.38mV. Roughness has been extracted from these images using Nano Scope Analysis 1.8 after a clean image treatment.

## Synthetic procedures

**QPTZ-Br** was synthesized as previously described.<sup>41</sup> The following procedures follow a previous report and are restated here for clarity.<sup>41</sup>

2-Bromospiro[fluorene-9,9'-quinolino[3,2,1-kl]phenothiazine] [**SQPT-2-FBr**]



1<sup>st</sup> step: The solution of **QPTZ-Br** (1.64 g, 4.63 mmol, 1.2 eq) in dry THF (50 mL) under argon was cooled to -78°C. *n*-BuLi (2.50 M in hexanes, 1.85 mL, 4.63 mmol, 1.2 eq) was then added dropwise and the resulting mixture was stirred for 30 min. 2-Bromofluorenone (1.00 g, 3.86 mmol, 1.0 eq) dissolved in dry THF (15 mL) at -78°C was added dropwise to the reaction mixture and stirred for 30 additional minutes. Then, the reaction was allowed to warm up to room temperature under stirring overnight. Solvent was removed under reduced pressure and the crude product was dried under vacuum at 60°C for 2 hours.

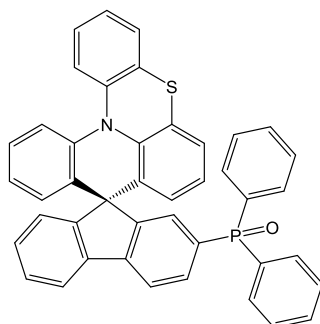
2<sup>nd</sup> step: Without further purification, the crude mixture was dissolved in acetic acid (50 mL) and hydrochloric acid (5 mL) was added under stirring. The reaction mixture was refluxed for 5 hours under stirring.

After cooling to room temperature, water was added to the reaction mixture. The precipitate was filtered off and then dissolved in CH<sub>2</sub>Cl<sub>2</sub>. The organic layer was washed with water and dried over MgSO<sub>4</sub>. Solvent was then removed under reduced pressure. A hot saturated solution of the crude in CHCl<sub>3</sub> was prepared and the product was precipitated by adding MeOH. This was repeated several times. Product was finally dried under vacuum at 40°C overnight.

After precipitation, from a mixture of CHCl<sub>3</sub>/MeOH, a white solid was obtained (1.74 g, yield 87 %). <sup>1</sup>H NMR (300 MHz, CD<sub>2</sub>Cl<sub>2</sub>) δ 7.80 (d, J = 8.1 Hz, 1H), 7.75 – 7.66 (m, 2H), 7.56 – 7.47 (m, 2H), 7.44 – 7.35 (m, 2H), 7.31 – 6.97 (m, 7H), 6.91 – 6.76 (m, 2H), 6.56 (dd, J = 7.9, 1.5 Hz, 1H), 6.37 (dd, J = 7.8, 1.4 Hz, 1H) ppm. <sup>13</sup>C NMR (75 MHz, CD<sub>2</sub>Cl<sub>2</sub>): δ 154.3 (C), 153.1 (C), 143.5 (C), 142.2 (C), 139.6 (2C), 136.7 (C), 132.5 (C), 132.3 (CH), 130.6 (CH), 130.4 (C), 129.2 (CH), 129.1 (CH), 128.5 (CH), 128.3 (CH), 128.2 (CH), 127.5 (CH), 127.4 (C), 126.6 (CH), 125.4 (CH), 125.2 (CH), 125.0 (C), 124.8 (CH), 124.5 (CH), 124.3 (CH), 122.5 (C), 122.2 (CH), 121.1 (CH), 120.7 (CH), 119.4 (CH), 57.9 (C) ppm. IR (ATR, platinum): 3062, 1916, 1771, 1703, 1653,

1590, 1580, 1566, 1506, 1489, 1478, 1455, 1436, 1404, 1321, 1302, 1289, 1271, 1255, 1231, 1215, 1190, 1160, 1131, 1123, 1111, 1082, 1063, 1035, 1006, 979, 962, 949, 934, 919, 885, 872, 853, 820, 789, 773, 745, 721, 696, 679, 654, 640, 622, 576, 550, 528, 507, 488, 472, 443, 433, 423  $\text{cm}^{-1}$ . HRMS (MALDI, DCTB): Found  $[\text{M}^+]$  515.033 for  $\text{C}_{31}\text{H}_{18}\text{BrNS}$  required 515.03378. m.p.: 262 °C

Diphenyl(spiro[fluorene-9,9'-quinolino[3,2,1-kl]phenothiazin]-2-yl)phosphine oxide [**SQPTZ-2-FPOP<sub>2</sub>**]



1<sup>st</sup> step: **SQPTZ-2-FBr** (0.500 g, 0.97 mmol, 1.0 eq) was dissolved in dry THF (45 mL) under argon. The reaction mixture was then cooled to -78°C and *n*-BuLi (2.50 M in hexanes, 0.58 mL, 1.45 mmol, 1.5 eq) was added dropwise. The reaction mixture was stirred for 2 hours at -78°C. Chlorodiphenylphosphine (0.27 mL, 1.45 mmol, 1.5 eq) was then added and the mixture was stirred for 2 additional hours at -78°C. The reaction mixture was finally allowed to warm up to room temperature under stirring overnight. The reaction mixture was quenched with few drops of absolute ethanol and concentrated under reduced pressure. The crude product was dissolved in  $\text{CH}_2\text{Cl}_2$ . The organic layer was washed with water, brine, dried over  $\text{MgSO}_4$  and filtered. Solvent was removed under reduced pressure and dried under vacuum at 60°C for 5 hours.

2<sup>nd</sup> step: Without any further purification, the crude mixture was dissolved in  $\text{CH}_2\text{Cl}_2$  (50 mL) and  $\text{H}_2\text{O}_2$  (5 mL, 35 wt. % in water) was added to the mixture which was stirred overnight at room temperature. The organic layer was washed several times with water and dried over  $\text{MgSO}_4$ . Solvent was then evaporated under reduced pressure and the crude product was purified with flash chromatography on silica gel [column condition: silica cartridge (40 g); solid deposit on Celite®;  $\lambda$  detection: (254 nm, 280 nm); gradient  $\text{CH}_2\text{Cl}_2/\text{CH}_3\text{OH}$  from 100 % to 95 % in 40 min at 40 mL/min]. The *title compound* was obtained as a white solid 0.311 g 50 %  $^1\text{H}$  NMR (300 MHz,  $\text{CD}_2\text{Cl}_2$ )  $\delta$  8.01 (dd,  $J = 7.8, 2.4$  Hz, 1H), 7.80 (d,  $J = 7.6$  Hz, 1H), 7.72 – 7.23 (m, 17H), 7.23 – 7.00 (m, 5H), 6.84 (t,  $J = 7.6$  Hz, 1H), 6.77 (t,  $J = 7.7$  Hz, 1H), 6.52 (dd,  $J = 8.0, 1.5$  Hz, 1H), 6.36 – 6.28 (m, 1H) ppm.  $^{13}\text{C}$  NMR (75 MHz,  $\text{CD}_2\text{Cl}_2$ )  $\delta$  155.0 (C), 151.0 (C), 146.7 (C), 143.3 (C), 139.7 (C), 139.5 (C), 136.5 (C), 134.3 (C), 134.1 (C), 133.2 (C), 132.9 (CH), 133.0 (CH), 132.6 (CH), 132.4 (CH), 131.2 (CH), 131.1 (CH), 130.4 (C), 130.1 (CH), 129.1 (CH), 129.0 (CH), 129.0 (CH), 128.5 (CH), 128.3 (CH), 128.2 (CH), 127.4 (C), 127.2 (CH), 126.5 (CH), 125.2 (CH), 125.1 (C), 125.0 (CH), 124.6 (CH), 124.4 (CH), 124.4 (CH), 121.9 (CH), 121.0 (CH),

120.8 (CH), 120.6 (CH), 119.4 (CH), 58.0 (C) ppm. <sup>31</sup>P NMR (121 MHz, CD<sub>2</sub>Cl<sub>2</sub>) δ 27.4 ppm. IR (ATR, platinum): 3671, 3416, 3055, 1606, 1588, 1569, 1488, 1477, 1454, 1436, 1403, 1323, 1314, 1291, 1270, 1252, 1229, 1203, 1185, 1170, 1160, 1148, 1129, 1116, 1106, 1083, 1070, 1035, 1026, 998, 929, 918, 893, 869, 855, 834, 800, 782, 746, 722, 703, 695, 681, 668, 644, 621, 592, 555, 542, 517, 488, 465, 443, 420 cm<sup>-1</sup>. HRMS (MALDI, DCTB): Found [M<sup>+</sup>] 637.164 for C<sub>43</sub>H<sub>28</sub>NOPS required 637.16237. m.p.: 185 °C

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